

2-input NOR Gate

REJ03D0200-0500Z (Previous ADE-205-015C (Z)) Rev.5.00 Jan.30.2004

### Description

The HD74UH02 is high-speed CMOS two input NOR gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high-speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output.

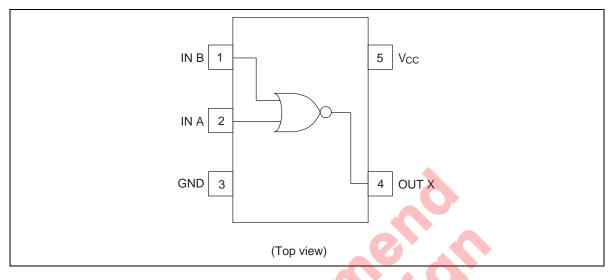
### Features

- Encapsulated in very small 5pins package of  $2.9 \times 1.6 \times 1.1$  mm, the efficiency to mount on substrate is significantly improved.
- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Electrical characteristics equivalent to the HD74HC02 Supply voltage range: 2 to 6 V Operating temperature range: -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74UH02EL	MPAK-5 pin	MPAK-5V	_	EL (3,000 pcs/reel)



## **Pin Arrangement**



# **Article Indication**

Marking Lot number

# Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	V <sub>CC</sub>	-0.5 to +7.0	V
Input voltage	V <sub>IN</sub>	–0.5 to V <sub>CC</sub> +0.5	V
Output voltage	V <sub>OUT</sub>	–0.5 to V <sub>CC</sub> +0.5	V
Input diode current	I <sub>IK</sub>	±20	mA
Output diode current	Ι <sub>ΟΚ</sub>	±20	mA
Output current	I <sub>OUT</sub>	±25	mA
V <sub>CC</sub> /GND current	I <sub>CC</sub> , I <sub>GND</sub>	±25	mA
Power dissipation	PT	200	mW
Storage temperature	Tstg	-65 to +150	°C



# **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit
Supply voltage	V <sub>CC</sub>	2 to 6	V
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	Topr	-40 to +85	°C
Input rise/fall time	t <sub>r</sub> , t <sub>f</sub>	0 to 1000 (V <sub>CC</sub> = 2.0 V)	ns
		0 to 500 ( $V_{CC} = 4.5 V$ )	
		0 to 400 ( $V_{CC} = 6.0 \text{ V}$ )	

# **Electrical Characteristics**

Electrical Characteristics									0			
		Vcc	Ta = 2	25°C		Ta = -4	40 to 85°C	3				
Item	Symbol	(V)	Min	Тур	Max	Min	Max	Unit	Test Condition	ıs		
Input voltage	V <sub>IH</sub>	2.0	1.5		_	1.5		V				
		4.5	3.15	_		3.15	-	6				
		6.0	4.2	_	-	4.2						
	VIL	2.0	_	—	0.5	-) '	0.5	V				
		4.5	_	-(	1.35	_	1.35					
		6.0	-	-	1.8		1.8					
Output voltage	V <sub>OH</sub>	2.0	1.9	2.0	-	1.9	_	V	$V_{\text{IN}} = V_{\text{IL}}$	I <sub>OH</sub> = -20 μA		
		4.5	4.4	4.5		4.4	_	_				
		6.0	5.9	6.0	-	5.9	_					
		4.5	4.18	4.31		4.13	_			$I_{OH} = -2 \text{ mA}$		
		6.0	5.68	5.80	_	5.63	_			$I_{OH} = -2.6 \text{ mA}$		
	Vol	2.0	$\mathbf{-}$	0.0	0.1	—	0.1	V	$V_{\text{IN}} = V_{\text{IH}} \text{ or } V_{\text{IL}}$	$I_{OL} = 20 \ \mu A$		
		4.5	—	0.0	0.1	_	0.1					
		6.0	_	0.0	0.1	_	0.1					
		4.5	_	0.17	0.26	_	0.33			$I_{OL} = 2 \text{ mA}$		
		6.0	—	0.18	0.26	—	0.33			$I_{OL} = 2.6 \text{ mA}$		
Input current	l <sub>iN</sub>	6.0	—		±0.1	_	±1.0	μA	$V_{IN} = V_{CC}$ or GN	ND		
Operating current	Icc	6.0	_		1.0	_	10.0		$V_{IN} = V_{CC}$ or GN	1D		

### **Switching Characteristics**

 $(C_L = 15 \text{ pF}, t_r = t_f = 6 \text{ ns}, V_{CC} = 5 \text{ V})$ 

		Ta = 2	25°C				
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Output rise/fall time	t <sub>TLH</sub> t <sub>THL</sub>	_	5	10	ns	See Test circuit	
Propagation delay time	t <sub>PLH</sub> t <sub>PHL</sub>		7	15	ns	See Test circuit	

 $(C_L = 50 \text{ pF}, t_r = t_f = 6 \text{ ns})$ 

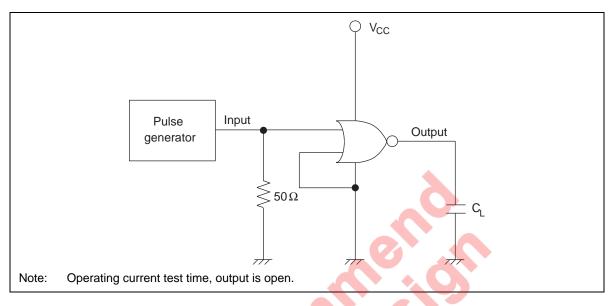
		$\mathbf{V}_{\text{cc}}$	Ta = 25°C			Ta = -40 to 85°C			
Item	Symbol	(V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Output rise/fall time	t <sub>TLH</sub>	2.0	_	50	125	-	155	ns	See Test circuit
	t <sub>⊤HL</sub>	4.5	_	14	25	-	31		
		6.0	_	12	21	-	26		
Propagation delay time	t <sub>PLH</sub>	2.0	_	48	100	-	125	ns	See Test circuit
	t <sub>PHL</sub>	4.5	-	12	20	-0	25	_	
		6.0		9	17	—	21		
Input capacitance	CIN	7		5	10		10	pF	
Equivalent capacitance	C <sub>PD</sub>	-	-	10		_	_	_	

Note: C<sub>PD</sub> is equivalent capacitance inside of the IC calculated from the operating current without load (see test circuit). The average operating current without load is calculated according to the expression below.

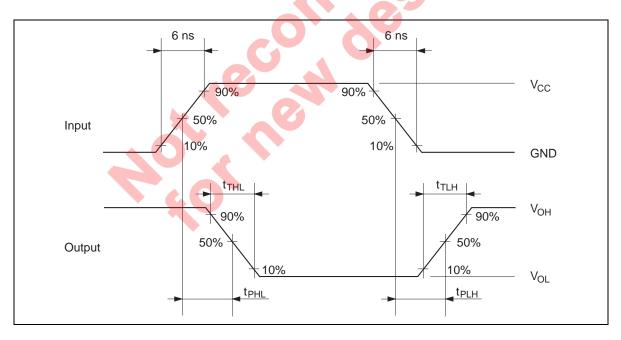
 $I_{CC}(opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 



## **Test Circuit**

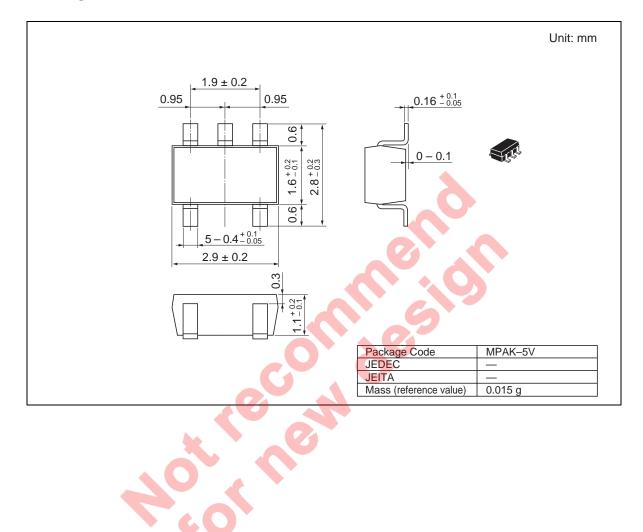


# Waveforms





## **Package Dimensions**





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